

Substitute for Form 1449/PTO

INFORMATION DISCLOSURE

STATEMENT BY APPLICANT

(use as many sheets as necessary)

Complete if Known

Application Number	09/912,495
Filing Date	July 24, 2001
First Named Inventor:	Steve Ghanayem
Art Unit	1762
Examiner Name	Meeks, Timothy H.
Attorney Docket Number	005049 USA/DSM/PMD/JW

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of 2

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (If known)				
T km		us-	2002/0000195 A1	01-03-2002	Bang et al.	RECEIVED OCT 14 2003 TC 1700
		us-	4,557,950	12-10-1985	Foster et al.	
		us-	5,356,722	10-18-1994	Nguyen et al.	
		us-	6,030,445	02-29-2000	Gregg et al.	
		us-	6,091,121	07-18-2000	Oda	
		us-	6,121,164	09-19-2000	Yieh et al.	
		us-				
		us-				
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		us-				
		us-				

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
		Country Code ⁴	Number ⁴ Kind Code ⁵ (if known)				
Tkm		EP	0 843 348 A2	05-20-1998	Applied Materials, Inc.		

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11/21/03

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language translation is attached.

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NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
THM		KERN, WERNER, ET AL., Simultaneous deposition and fusion flow planarization of borophosphosilicate glass in a new chemical vapor deposition reactor, Thin Solid Films, Elsevier-Sequoia S.A., Lausanne, CH, Vol. 206, No. 1/2, December 10, 1991, pages 64-69, XP000355313, ISSN: 0040-6090.	
THM		MURRELL, ADRIAN J., ET AL., Characterisation of Ultra-Shallow Junctions Using Advanced SIMS, SRP and HRTEM Techniques, Applied Materials, Implant Division, Foundry Lane, Horsham, W. Sussex, RH13 5PY, UK. 5 pages.	
THM		ROBLES, STUARDO, ET AL., Gap Fill and Film Reflow Capability of Subatmospheric Chemical Vapor Deposited Borophosphosilicate Glass, Reprinted from Journal Of The Electrochemical Society, Vol. 143, No. 4, April 1996, ©1995, pgs. 1414-1421.	
THM		XIA, L.-Q., ET AL., Process Characteristics for Subatmospheric Chemical Vapor Deposited Borophosphosilicate Glass and Effect of Carrier Gas, Reprinted from Journal Of The Electrochemical Society, Vol. 144, No. 9, September 1997, © 1997, pgs. 3208-3212.	
THM		XIA, L.-Q., ET AL., High Aspect Ratio Trench Filling Using Two-Step Subatmospheric Chemical Vapor Deposited Borophosphosilicate Glass for <0.18 µm Device Application, Journal of The Electrochemical Society, Manchester, New Hampshire, U.S.A., Vol. 146, No. 5, May 1999, pages 1884-1888, XP001002961, ISSN: 0013-4651	
THM		Search Report for PCT/US 02/22608, mailed November 7, 2002, 4 pages.	
THM		Search Report for PCT/US 02/23520, mailed November 25, 2002, 5 pages.	

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